

PATENT
29925/37672

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Young-Hun Bae and
Won-Sung Park

Serial No.: 09/940,774

Filed: August 27, 2001

For: Method for Forming a Gate
of a High Integration
Semiconductor Device

Group Art Unit: 2823

Examiner: William M. Brewster

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AMENDMENT

Commissioner for Patents
P.O. Box 1450 Alexandria
Virginia 22313-1450

Dear Sir:

Please enter the following amendment in the above-referenced patent
application.